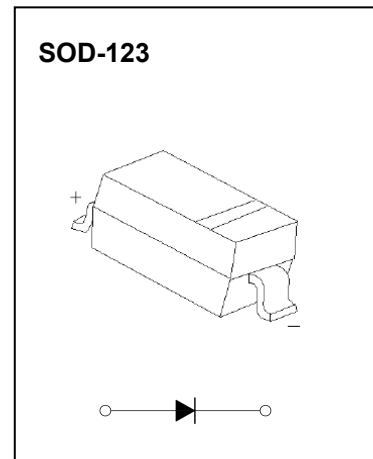


FEATURES

For use in low voltage, high frequency inverters
 Free wheeling, and polarity protection applications.

MARKING: SJ



Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	K1N5817HW-7-F	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	20	V
Peak Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	V
RMS Reverse Voltage	$V_{R(RMS)}$	14	V
Average Rectified Output Current	I_O	1	A
Peak Forward Surge Current @t=8.3ms	I_{FSM}	9	A
Repetitive Peak Forward Current	I_{FRM}	1.5	A
Power Dissipation	P_d	500	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	250	°C/W
Storage Temperature	T_{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R = 1mA$	20		V
Reverse voltage leakage current	I_R	$V_R = 20V$		1	mA
Forward voltage	V_F	$I_F = 1A$ $I_F = 3A$		0.45 0.75	V
Diode capacitance	C_D	$V_R = 4V, f = 1MHz$		120	pF

Typical Characteristics

